BYV29G-600

Ultrafast rectifier diode Rev. 01 — 4 February 2010

Product data sheet

1. Product profile

1.1 General description

Ultrafast epitaxial rectifier diode in a SOT226 (I2PAK) plastic package

1.2 Features and benefits

- Fast switching
- High thermal cycling performance
- Low forward voltage drop
- Low on-state losses

- Low profile package facilitating compact designs
- Low thermal resistance
- Soft recovery minimizes power-consuming oscillations

1.3 Applications

■ Discontinuous Current Mode (DCM) Power Factor Correction (PFC)

Output rectifiers in high-frequency switched-mode power supplies

1.4 Quick reference data

Table 1. **Quick reference**

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{RRM}	repetitive peak reverse voltage		-	-	600	V
I _{F(AV)}	average forward current	square-wave pulse; $\delta = 0.5$; $T_{mb} \le 123$ °C; see <u>Figure 1</u> and <u>2</u>	-	-	9	Α
I _{FRM}	repetitive peak forward current	$t_p = 25 \ \mu s; \ \delta = 0.5$	-	-	18	Α
Dynamic	characteristics					
t _{rr}	reverse recovery time	$I_F = 1 \text{ A}; V_R = 30 \text{ V};$ $dI_F/dt = 100 \text{ A/}\mu\text{s};$ $T_j = 25 \text{ °C}; \text{ see } \frac{\text{Figure 5}}{}$	-	50	60	ns
Static ch	naracteristics					
V _F	forward voltage	$I_F = 8 \text{ A}; T_j = 150 \text{ °C};$ see Figure 4	-	0.97	1.11	V



2. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	n.c.	no connection		2
2	K	cathode		2
3	Α	anode	0	1 1 3
mb	К	mounting base; cathode		003aad550
			SOT226A (I2PAK)	

3. Ordering information

Table 3. Ordering information

Type number	Package			
	Name	Description	Version	
BYV29G-600	I2PAK	plastic single-ended package (I2PAK); TO-262	SOT226A	

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{RRM}	repetitive peak reverse voltage		-	600	V
V_{RWM}	crest working reverse voltage		-	600	V
V_R	reverse voltage	DC	-	600	V
I _{F(AV)}	average forward current	square-wave pulse; δ = 0.5; $T_{mb} \le$ 123 °C; see Figure 1 and 2	-	9	Α
I _{FSM}	non-repetitive peak	$t_p = 8.3$ ms; sine-wave pulse; $T_{j(init)} = 25$ °C	-	77	Α
	forward current	t_p = 10 ms; sine-wave pulse; $T_{j(init)}$ = 25 °C	-	70	Α
T _{stg}	storage temperature		-40	150	°C
Tj	junction temperature		-	150	°C
I _{FRM}	repetitive peak forward current	t_p = 25 μ s; δ = 0.5	-	18	Α

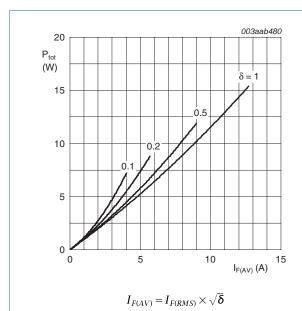
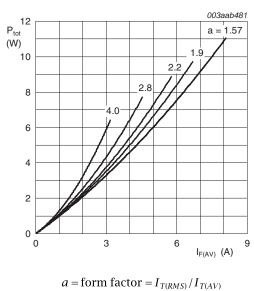


Fig 1. Forward power dissipation as a function of average forward current; square waveform; maximum values



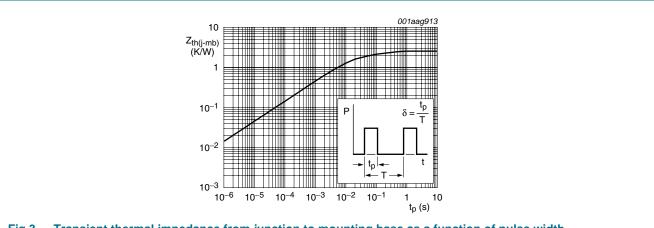
 $u = 101111140001 = T_{I(RMS)}/T_{I(AV)}$

Fig 2. Forward power dissipation as a function of average forward current; sinusoidal waveform; maximum values

Thermal characteristics

Table 5. **Thermal characteristics**

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-mb)}$	thermal resistance from junction to mounting base	with heatsink compound; see Figure 3	-	-	2.5	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient free air		-	60	-	K/W



Transient thermal impedance from junction to mounting base as a function of pulse width

6. Characteristics

Table 6. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
•	racteristics			71		
V _F	forward voltage	$I_F = 8 \text{ A}$; $T_j = 25 \text{ °C}$; see Figure 4	-	1.12	1.25	V
		I _F = 20 A; T _j = 25 °C; see <u>Figure 4</u>	-	1.31	1.45	V
		I _F = 8 A; T _j = 150 °C; see <u>Figure 4</u>	-	0.97	1.11	V
I _R	reverse current	V _R = 600 V	-	2	50	μΑ
		V _R = 600 V; T _j = 100 °C	-	0.1	0.35	mA
Dynamic	characteristics					
Q _r	recovered charge	$I_F = 2 \text{ A}$; $V_R = 30 \text{ V}$; $dI_F/dt = 20 \text{ A/}\mu\text{s}$; see Figure 5	-	40	70	nC
t _{rr}	reverse recovery time	$I_F = 1 \text{ A}$; $V_R = 30 \text{ V}$; $dI_F/dt = 100 \text{ A/}\mu\text{s}$; $T_j = 25 \text{ °C}$; see Figure 5	-	50	60	ns
I _{RM}	peak reverse recovery current	$I_F = 10 \text{ A}$; $V_R = 30 \text{ V}$; $dI_F/dt = 50 \text{ A/}\mu\text{s}$; see Figure 5	-	3	5.5	Α
V_{FR}	forward recovery voltage	$I_F = 10 \text{ A}$; $dI_F/dt = 10 \text{ A/}\mu\text{s}$; see Figure 6	-	3.2	-	V

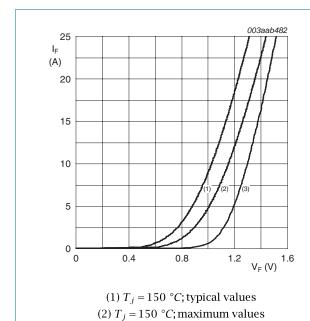


Fig 4. Forward current as a function of forward voltage

(3) $T_j = 25$ °C; maximum values

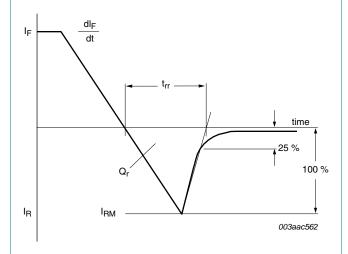


Fig 5. Reverse recovery definitions; ramp recovery

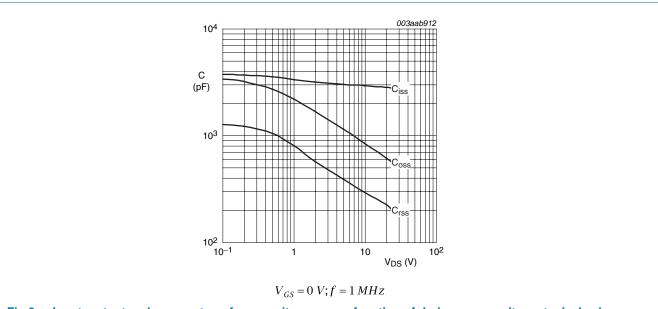


Fig 6. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

7. Package outline

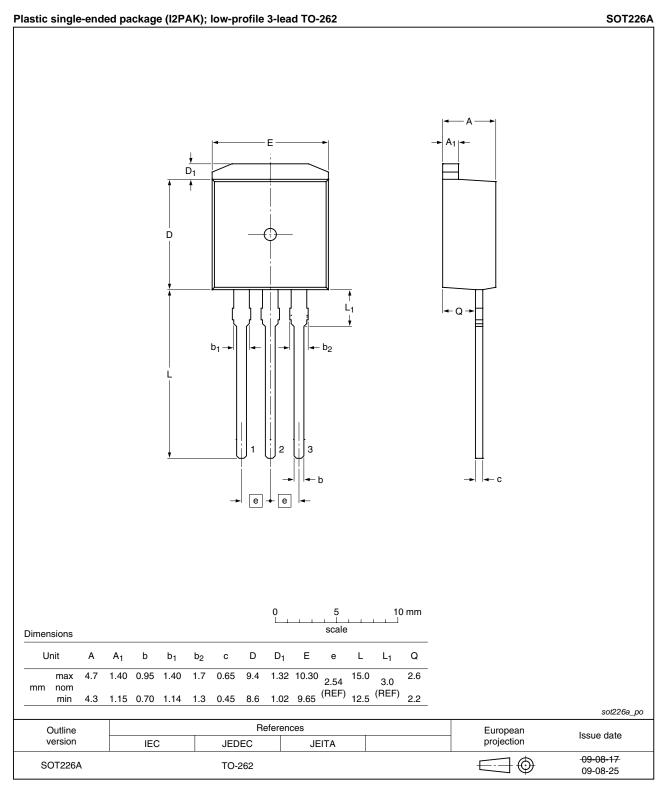


Fig 7. Package outline SOT226A (I2PAK)



8. Revision history

Table 7. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BYV29G-600_1	20100204	Product data sheet	-	-

9. Legal information

9.1 Data sheet status

Document status [1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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